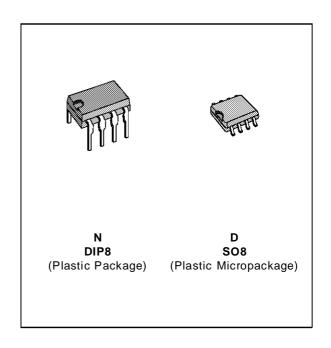


LM101A - LM201A LM301A

SINGLE OPERATIONAL AMPLIFIERS

	LM101A	LM301A
	LM201A	LIVISUTA
■ INPUT OFFSET VOLTAGE	0.7mV	2mV
■ INPUT BIAS CURRENT	25nA	70nA
■ INPUT OFFSET CURRENT	1.5nA	2nA
■ SLEW RATE AS INVERTIN	G	
AMPLIFIER	10V/μs	10V/μs



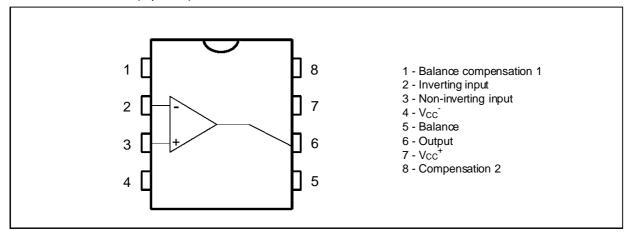
DESCRIPTION

The LM101A is a general-purpose operational amplifier. This amplifier offers many features : supply voltages from ± 5 V to ± 22 V, low current drain, overload protection on the input and output, no latch-up when the common-mode range is exceeded, freedom from oscillations and compensation with a single 30pF capacitor. It has advantages over internally compensated amplifiers in that the compensation can be tailored to the particular application : slew rates of 10 V/µs and bandwidths of 3.5MHz can be easily achieved.

ORDER CODES

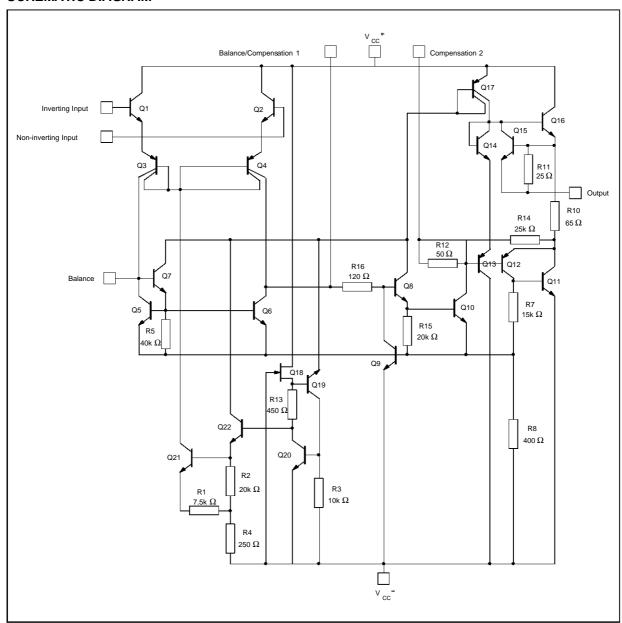
Part Number	Temperature	Package				
Fait Number	Range	N	D			
LM101A	–55, +125°C	•	•			
LM201A	–40, +105°C	•	•			
LM301A	•	•				
Example: LM201AN						

PIN CONNECTIONS (top view)



April 1995 1/11

SCHEMATIC DIAGRAM



ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter		LM101A	LM201A	LM301A	Unit
Vcc	Supply Voltage		±22	±22	±22	V
V_{id}	Differential Input Voltage		±30	±30	±30	V
Vi	Input Voltage		±15	±15	V	
	Output Short-circuit Duration		Infinite			
P _{tot}	Power Dissipation	N Suffix D Suffix		mW		
T _{oper}	Operating Free-air Temperature	Range	-55 to +125 -40 to +105 0 to +70			°C
T _{stg}	Storage Temperature Range		-65 to +150	°C		

ELECTRICAL CHARACTERISTICS

LM301A 0° C < Tamb < $+70^{\circ}$ C ± 5 V \leq V_{CC} \leq ± 20 VC1 = 30pFLM201A -40° C < Tamb < $+105^{\circ}$ C ± 5 V \leq V_{CC} \leq ± 20 VC1 = 30pFLM101A -55° C < Tamb < $+125^{\circ}$ C ± 5 V \leq V_{CC} \leq ± 20 VC1 = 30pF

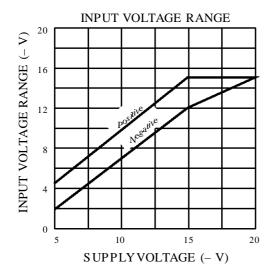
* => $V_{CC} = \pm 15V$, $T_{amb} = 25^{\circ}C$ (unless otherwise specified)

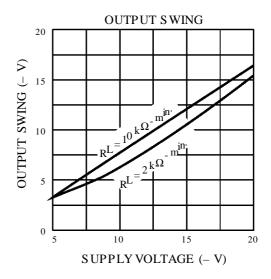
Cumbal	Parameter	LM10)1A - LN	1201A	LM301A			Unit
Symbol	Parameter	Min. Typ. Max.				Тур.	Max.	Onit
V _{io}	Input Offset Voltage ($R_S \le 10 k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$		0.7	2 3		2	7.5 10	mV
l _{ib}			25	75 100		70	250 300	nA
l _{io}			1.5	10 20		2	50 70	nA
A _{vd}	Large Signal Voltage Gain *	50 25	100		25 15	100		V/mV
SVR	Supply Voltage Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	80 80	96		70 70	96		dB
Icc	Supply Current no Load $ \begin{array}{l} T_{amb} = 25^{\circ}C \\ T_{min} \leq T_{amb} \leq T_{max}. \end{array} $		1.8	3 3		1.8	3 3	mA
Vicm	Input Common Mode Voltage Range $(V_{CC} = \pm 20V)$ $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	±15 ±15			±15 ±15			V
CMR	Common Mode Rejection Ratio ($R_S \le 10k\Omega$) $T_{amb} = 25^{\circ}C$ $T_{min.} \le T_{amb} \le T_{max.}$	80 80	96		70 70	96		dB
los	Output Short-circuit Current * T _{amb} = 25°C	10	30	50	10	30	50	mA
± V _{OPP}	$\label{eq:controller} \begin{split} & \text{Output Voltage Swing *} \\ & & T_{amb} = 25^{\circ}\text{C} \\ & & R_{L} = 10k\Omega \\ & & R_{L} = 2k\Omega \\ & T_{min.} \leq T_{amb} \leq T_{max.} \\ & & R_{L} = 10k\Omega \\ & & R_{L} = 2k\Omega \end{split}$	12 10 12 10	14 13		12 10 12 10	14 13		V

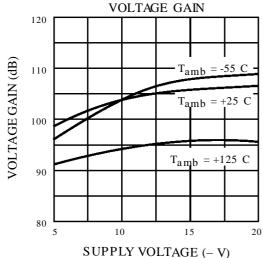
ELECTRICAL CHARACTERISTICS (continued)

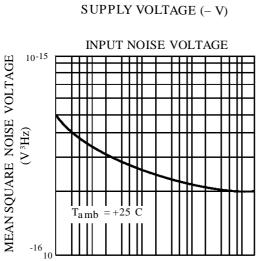
Cumbal	Parameter	LM10	1A - LM	201A	LM301A			- Unit
Symbol	rarameter		Тур.	Max.	Min.	Тур.	Max.	Unit
SR	Slew Rate ($V_I = \pm 10V$, $R_L = 2k\Omega$, $C_L = 100pF$, $T_{amb} = 25^{\circ}C$, unity gain) - (note 1) *	0.25	0.5		0.25	0.5		V/μs
t _r	Rise Time $(V_I = \pm 20 \mu V, R_L = 2k\Omega, C_L = 100 pF, T_{amb} = 25^{5}C$, unity gain) *		0.3			0.3		μs
Kov	Overshoot ($V_I = 20 \text{ mV}$, $R_L = 2k\Omega$, $C_L = 100 \text{pF}$, $T_{amb} = 25^{\circ}\text{C}$, unity gain)		5			5		%
Zi	Input Impedance *	1.5	4		1.5	4		МΩ
Ro	Output Resistance *		75			75		Ω
GBP	Gain Bandwidth Product * $(V_I = 10 \text{mV}, R_L = 2 \text{k}\Omega, C_L = 100 \text{pF}, f = 100 \text{kHz}, T_{amb} = 25^{\circ}\text{C})$	0.5	1		0.5	1		MHz
THD	Total Harmonic Distortion (f = 1kHz, A_V = 20dB, R_L = 2k Ω , V_O = 2V _{PP} , C_L = 100pF, T_{amb} = 25°C)		0.015			0.015		%
en	Equivalent Input Noise Voltage (f = 1kHz, $R_s = 100\Omega$)		25			25		$\frac{\text{nV}}{\sqrt{\text{Hz}}}$
DV _{io}	Input Offset Voltage Drift $T_{min.} \le T_{amb} \le T_{max.}$		3	15		6	30	μV/°C
DI _{io}	$\begin{array}{l} \text{Input Offset Current Drift} \\ 25^{\circ}C \leq T_{amb} \leq T_{max.} \\ T_{min.} \leq T_{amb} \leq 25^{\circ}C \end{array}$		10 20	100 200		10 20	300 600	pA/°C

Note: 1. May be improved up to $10V/\mu s$ in inverting amplifier configuration (see basic diagram).







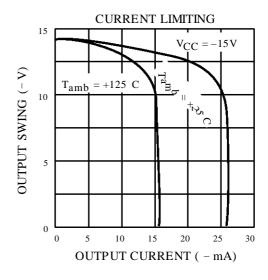


1k FREQUENCY (Hz)

10k

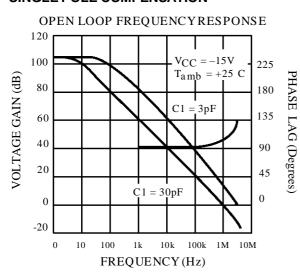
100k

SUPPLY CURRENT 2.5 $T_{amb} = -55 C$ SUPPLY CURRENT (mA) 5.0 c c c $T_{amb} = +25 C$ SUPPLY VOLTAGE (- V)

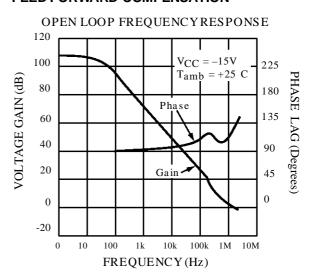


SINGLE POLE COMPENSATION

10



FEED FORWARD COMPENSATION



SINGLE POLE COMPENSATION

10k

0 L

LARGE SIGNAL FREQUENCY RESPONSE

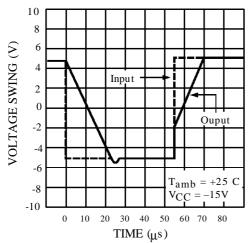
VOLTAGE FOLLOWER PULSE RESPONSE

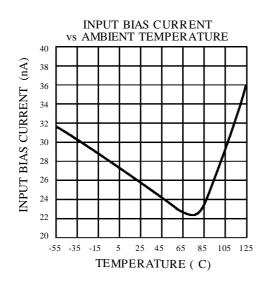
100K

FREQUENCY (Hz)

1M

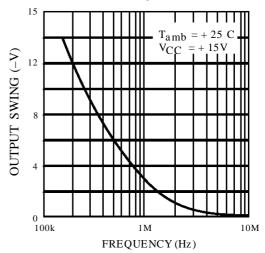
10M



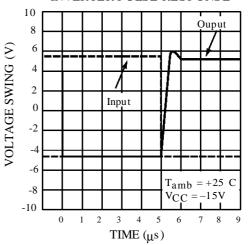


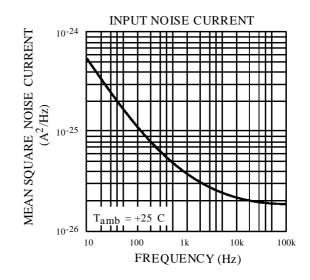
FEED FORWARD COMPENSATION

LARGE SIGNAL FREQUENCY RESPONSE



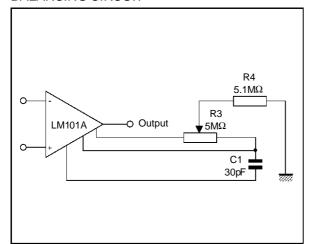
INVERTER PULSE RESPONSE



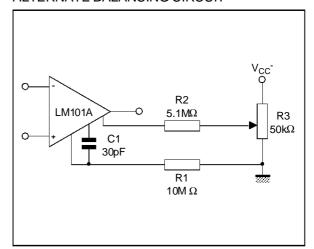


BASIC DIAGRAM

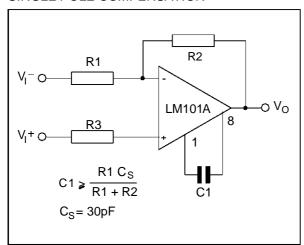
BALANCING CIRCUIT



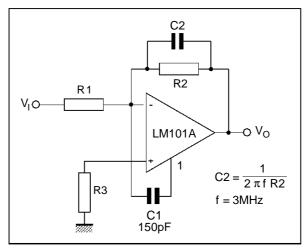
ALTERNATE BALANCING CIRCUIT



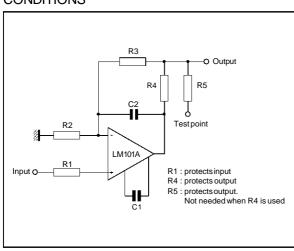
SINGLE POLE COMPENSATION



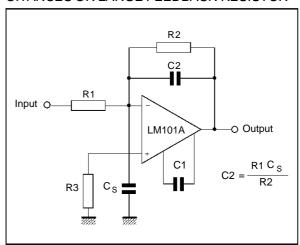
FEEDFORWARD COMPENSATION



PROTECTING AGAINST GROSS FAULT CONDITIONS

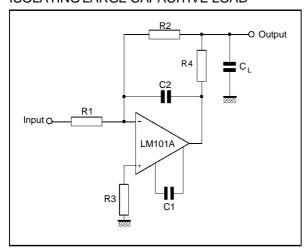


COMPENSATING FOR STRAY INPUT CAPA CITANCES OR LARGE FEEDBACK RESISTOR

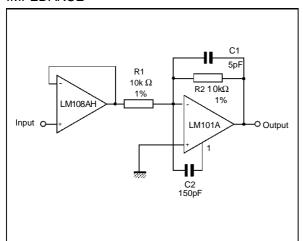


BASIC DIAGRAM (continued)

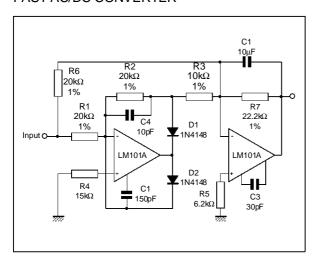
ISOLATING LARGE CAPACITIVE LOAD



FAST AMPLIFIER WITH HIGH INPUT IMPEDANCE

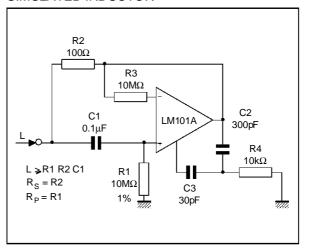


FAST AC/DC CONVERTER

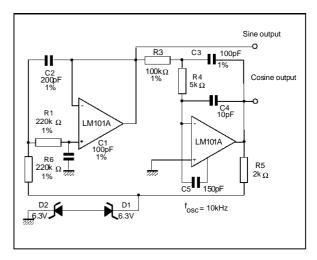


TYPICAL APPLICATIONS

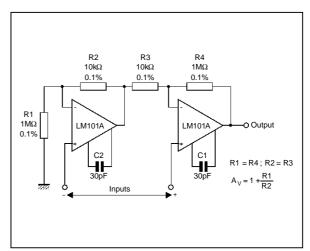
SIMULATED INDUCTOR



SINE WAVE OSCILLATOR



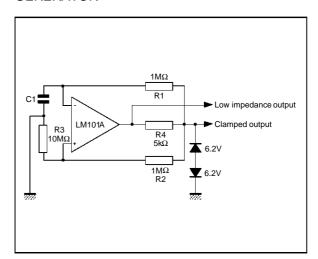
INSTRUMENTATION AMPLIFIER



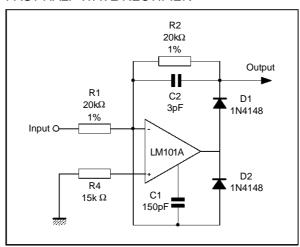
TYPICAL APPLICATIONS (continued)

VARIABLE CAPACITANCE MULTIPLIER

LOW FREQUENCY SQUARE WAVE GENERATOR

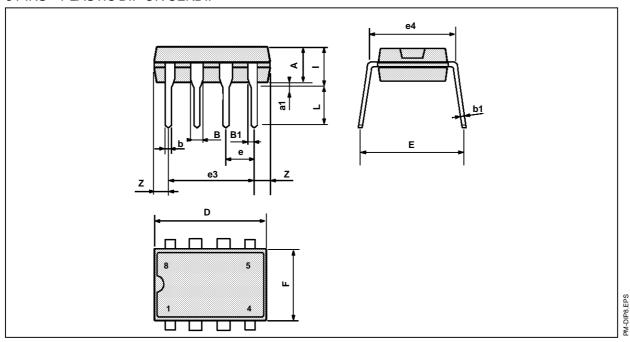


FAST HALF WAVE RECTIFIER



PACKAGE MECHANICAL DATA

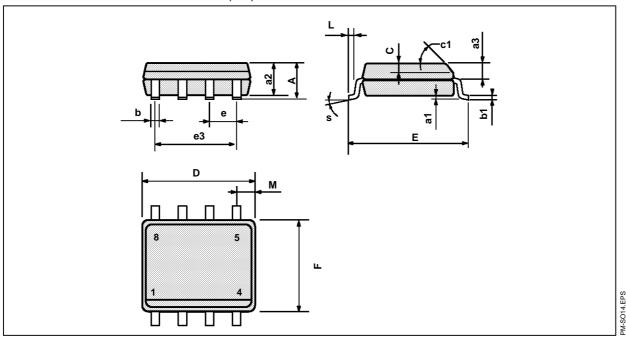
8 PINS - PLASTIC DIP OR CERDIP



Dimensions		Millimeters				
Dimensions	Min.	Тур.	Max.	Min.	Тур.	Max.
А		3.32			0.131	
a1	0.51			0.020		
В	1.15		1.65	0.045		0.065
b	0.356		0.55	0.014		0.022
b1	0.204		0.304	0.008		0.012
D			10.92			0.430
E	7.95		9.75	0.313		0.384
е		2.54			0.100	
e3		7.62			0.300	
e4		7.62			0.300	
F			6.6			0260
i			5.08			0.200
L	3.18		3.81	0.125		0.150
Z			1.52			0.060

PACKAGE MECHANICAL DATA

8 PINS - PLASTIC MICROPACKAGE (SO)



Dimensions	Millimeters			Inches				
Dillicusions	Min.	Тур.	Max.	Min.	Тур.	Max.		
А			1.75			0.069		
a1	0.1		0.25	0.004		0.010		
a2			1.65			0.065		
a3	0.65		0.85	0.026		0.033		
b	0.35		0.48	0.014		0.019		
b1	0.19		0.25	0.007		0.010		
C	0.25		0.5	0.010		0.020		
c1		•	45°	(typ.)	•	•		
D	4.8		5.0	0.189		0.197		
Е	5.8		6.2	0.228		0.244		
е		1.27			0.050			
e3		3.81			0.150			
F	3.8		4.0	0.150		0.157		
L	0.4		1.27	0.016		0.050		
М			0.6			0.024		
S	8° (max.)							

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